

DRV8313 TRIPLE HALF-H-BRIDGE DRIVER IC

Check for Samples: DRV8313

FEATURES

- Three Half-H-Bridge Driver IC
 - Drives 3-Phase Brushless DC Motors
 - Individual Half-Bridge Control
 - Pins for Low-Side Current Sensing
 - Low MOSFET On-Resistance
- 2.5-A Maximum Drive Current at 24 V, 25°C
- Uncommitted Comparator Can Be Used for Current Limit or Other Functions
- Built-In 3.3-V 10-mA LDO Regulator
- 8-V to 60-V Operating Supply Voltage Range
- Thermally Enhanced Surface-Mount Package

APPLICATIONS

- HVAC Motors
- Consumer Products
- Office Automation Machines
- Factory Automation
- Robotics

DESCRIPTION

The DRV8313 provides three individually controllable half-H-bridge drivers. It is intended to drive a three-phase brushless dc motor, though it can also be used to drive solenoids or other loads. Each output driver channel consists of N-channel power MOSFETs configured in a half-H-bridge configuration. The design brings the ground terminals of each driver to pins, to allow one to perform current sensing on each output.

Current-limit circuitry or other functions are possible uses of an uncommitted comparator.

The DRV8313 can supply up to 2.5-A peak or 1.75-A rms output current per channel (with proper PCB heatsinking at 24 V and 25°C) per half-H-bridge.

The device provides internal shutdown functions for overcurrent protection, short-circuit protection, undervoltage lockout, and overtemperature.

The DRV8313 comes in a 28-pin HTSSOP PowerPAD™ package.

ORDERING INFORMATION(1)

ORDERABLE PART NUMBER	PACKAGE ⁽²⁾	TOPSIDE MARKING	SHIPPING
DRV8313PWPR	LITCOOD DWD	DD\/0242	Reel of 2000
DRV8313PWP	HTSSOP – PWP	DRV8313	Tube of 50

For the most-current packaging and ordering information, see the Package Option Addendum at the end of this document, or see the TI
Web site at www.ti.com.

M

Please be aware that an important notice concerning availability, standard warranty, and use in critical applications of Texas Instruments semiconductor products and disclaimers thereto appears at the end of this data sheet.

PowerPAD is a trademark of Texas Instruments.

All other trademarks are the property of their respective owners.

⁽²⁾ See package drawings, thermal data, and symbolization at www.ti.com/packaging.

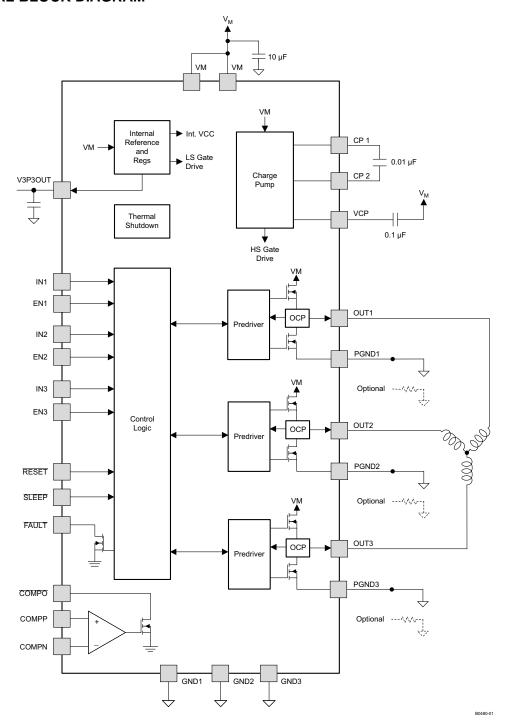




This integrated circuit can be damaged by ESD. Texas Instruments recommends that all integrated circuits be handled with appropriate precautions. Failure to observe proper handling and installation procedures can cause damage.

ESD damage can range from subtle performance degradation to complete device failure. Precision integrated circuits may be more susceptible to damage because very small parametric changes could cause the device not to meet its published specifications.

FUNCTIONAL BLOCK DIAGRAM

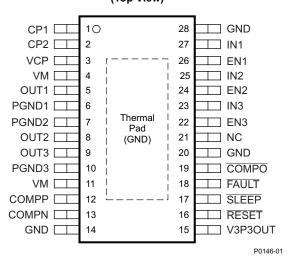


Submit Documentation Feedback

Copyright © 2012, Texas Instruments Incorporated



PWP Package (Top View)



PIN DESCRIPTIONS

P	PIN	TVDE	DECODIDATION	EVIEDNAL COMPONENTO OD COMMECTIONO				
NAME	NO.	TYPE	DESCRIPTION	EXTERNAL COMPONENTS OR CONNECTIONS				
Power and	l Ground							
CP1	1	Ю	Charge-pump flying capacitor	Connect a 0.04 uF 400 V connector between CR4 and CR2				
CP2	2	Ю	Charge-pump flying capacitor	Connect a 0.01-µF 100-V capacitor between CP1 and CP2.				
GND	12, 20, 28, PPAD	-	Device ground	Connect to system ground				
V3P3OUT	P3OUT 15 O 3.3-V regulator output		3.3-V regulator output	Bypass to GND with a $0.47-\mu F$ $6.3-V$ ceramic capacitor. Use for suppling external loads is permissible.				
VCP	3	Ю	High-side gate drive voltage	Connect a 0.1-µF 16-V ceramic capacitor to VM.				
VM	4, 11	-	Main power supply	Connect to power supply (8.2 V–60 V). Connect both pins to the same supply. Bypass to GND with a 10-µF (minimum) capacitor.				
Control								
EN1	26	1	Channel 1 enable	Logic high enables OUT1. Internal pulldown				
EN2	24	1	Channel 2 enable	Logic high enables OUT2. Internal pulldown				
EN3	22	1	Channel 3 enable	Logic high enables OUT3. Internal pulldown				
IN1	27	I	Channel 1 input	Logic input controls state of OUT1. Internal pulldown				
IN2	25	I	Channel 2 input	Logic input controls state of OUT2. Internal pulldown				
IN3	23	ı	Channel 3 input	Logic input controls state of OUT3. Internal pulldown				
nRESET	16	1	Reset input	Active-low reset input initializes internal logic and disables the outputs. Internal pulldown				
nSLEEP	17	1	Sleep-mode input	Logic high to enable device, logic low to enter low-power sleep mode. Internal pulldown				
Status								
nFAULT	18	OD	Fault	Logic low when in fault condition (overtemperature, overcurrent, UVLO)				
Comparate	or							
COMPN	13	1	Comparator negative input	Negative input of comparator				
COMPP	12	1	Comparator positive input	Positive input of comparator				
nCOMPO	19	OD	Comparator out	Output of comparator. Open-drain output				



PIN DESCRIPTIONS (continued)

PII	N	TYPE	DESCRIPTION	EVERNAL COMPONENTS OF CONNECTIONS			
NAME	NO.	ITPE	DESCRIPTION	EXTERNAL COMPONENTS OR CONNECTIONS			
Output							
OUT1	5	0	Output 1				
OUT2	8	0	Output 2	Connect to loads.			
OUT3	9	0	Output 3				
PGND1	6	-	Ground for OUT1				
PGND2	7	-	Ground for OUT2	Connect to ground, or to low-side current-sense resistors.			
PGND3	10	-	Ground for OUT3				

ABSOLUTE MAXIMUM RATINGS

over operating free-air temperature range (unless otherwise noted)(1)(2)

		VALUE	UNIT
	Power-supply voltage range (V _M)	−0.3 V to 65	V
	Digital-pin voltage range	-0.5 to 7	V
	Comparator input-voltage range	-0.5 to 7	V
	Peak motor-drive output current	Internally limited	Α
	Pin voltage (GND1, GND2, GND3)	±600	mV
	Continuous motor-drive output current (3)	2.5	А
TJ	Operating virtual junction temperature range	-40 to 150	°C
T _{stg}	Storage temperature range	-60 to 150	°C

⁽¹⁾ Stresses beyond those listed under Absolute Maximum Ratings may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under Recommended Operating Conditions is not implied. Exposure to absolute-maximum-rated conditions for extended periods may affect device reliability.

(2) All voltage values are with respect to the network ground terminal.

THERMAL INFORMATION

		DRV8313	
	THERMAL METRIC ⁽¹⁾	PWP	UNIT
		28 PINS	
θ_{JA}	Junction-to-ambient thermal resistance (2)	31.6	°C/W
θ_{JCtop}	Junction-to-case (top) thermal resistance ⁽³⁾	15.9	°C/W
θ_{JB}	Junction-to-board thermal resistance (4)	5.6	°C/W
ΨЈТ	Junction-to-top characterization parameter (5)	0.2	°C/W
ΨЈВ	Junction-to-board characterization parameter ⁽⁶⁾	5.5	°C/W
θ_{JCbot}	Junction-to-case (bottom) thermal resistance (7)	1.4	°C/W

- (1) For more information about traditional and new thermal metrics, see the IC Package Thermal Metrics application report, SPRA953.
- (2) The junction-to-ambient thermal resistance under natural convection is obtained in a simulation on a JEDEC-standard, high-K board, as specified in JESD51-7, in an environment described in JESD51-2a.
- (3) The junction-to-case (top) thermal resistance is obtained by simulating a cold plate test on the package top. No specific JEDEC-standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.
- (4) The junction-to-board thermal resistance is obtained by simulating in an environment with a ring cold plate fixture to control the PCB temperature, as described in JESD51-8.
- (5) The junction-to-top characterization parameter, ψ_{JT} , estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA} , using a procedure described in JESD51-2a (sections 6 and 7).
- (6) The junction-to-board characterization parameter, ψ_{JB}, estimates the junction temperature of a device in a real system and is extracted from the simulation data for obtaining θ_{JA}, using a procedure described in JESD51-2a (sections 6 and 7).
- (7) The junction-to-case (bottom) thermal resistance is obtained by simulating a cold plate test on the exposed (power) pad. No specific JEDEC standard test exists, but a close description can be found in the ANSI SEMI standard G30-88.

⁽³⁾ Observe power dissipation and thermal limits.



RECOMMENDED OPERATING CONDITIONS

over operating free-air temperature range (unless otherwise noted)

		MIN	NOM	MAX	UNIT
V_{M}	Motor power-supply voltage range (1)	8		60	V
V_{GNDX}	GND1, GND2, GND3 pin voltage	-500	0	500	mV
I _{V3P3}	V3P3OUT load current	0		10	mA

⁽¹⁾ All $V_{\rm M}$ pins must be connected to the same supply voltage.

ELECTRICAL CHARACTERISTICS

 $T_A = 25$ °C, over operating free-air temperature range (unless otherwise noted)

	PARAMETER	TEST CONDITIONS	MIN	TYP	MAX	UNIT
Power S	upplies				'	
I_{VM}	VM operating supply current	V _M = 24 V, f _{PWM} < 50 kHz		1	5	mA
I _{VMQ}	VM sleep-mode supply current	V _M = 24 V		500	800	μA
V _{UVLO}	VM undervoltage lockout voltage	V _M rising		6.3	8	V
	T Regulator					
V _{3P3}	V3P3OUT voltage	I _{OUT} = 0 to 10 mA	3.1	3.3	3.52	V
Logic-Le	evel Inputs				"	
V _{IL}	Input low voltage			0.6	0.7	V
V _{IH}	Input high voltage		2.2		5.25	V
V _{HYS}	Input hysteresis		50		600	mV
I _{IL}	Input low current	VIN = 0	-5		5	μA
I _{IH}	Input high current	VIN = 3.3 V			100	μA
R _{PD}	Pulldown resistance			100		kΩ
nFAULT	and COMPO OutputS (Open-Drain Ou	tputs)			•	
V _{OL}	Output low voltage	I _O = 5 mA			0.5	V
I _{OH}	Output high leakage current	V _O = 3.3 V			1	μA
Compara	ator				•	
V_{CM}	Common-mode input-voltage range		0		5	V
V _{IO}	Input offset voltage		-7		7	mV
I _{IB}	Input bias current		-300		300	nA
t _R	Response time	100-mV step with 10-mV overdrive			2	μs
H-Bridge	FETs				•	
_	High side CCT or resistance	V _M = 24 V, I _O = 1 A, T _J = 25°C		0.24		0
r _{ds(on)}	High-side FET on-resistance	V _M = 24 V, I _O = 1 A, T _J = 85°C		0.29	0.39	Ω
_	Lauraida FFT an maintanan	V _M = 24 V, I _O = 1 A, T _J = 25°C		0.24		0
r _{ds(on)}	Low-side FET on-resistance	V _M = 24 V, I _O = 1 A, T _J = 85°C		0.29	0.39	Ω
I _{OFF}	Off-state leakage current		-2		2	μΑ
t _{DEAD}	Output dead time			90		ns
Protection	on Circuits				•	
I _{OCP}	Overcurrent protection trip level		3			А
t _{OCP}	Overcurrent protection deglitch time			5		μs
T _{TSD}	Thermal shutdown temperature	Die temperature	150	160	180	°C

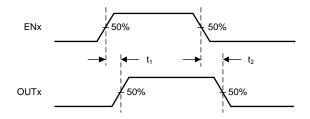


SWITCHING CHARACTERISTICS(1)

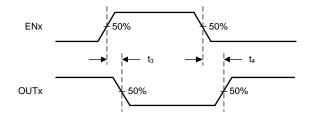
 $T_A = 25^\circ$, $V_M = 24$ V, $R_L = 20$ Ω

NO.	PARAMETER	DESCRIPTION	MIN	MAX	UNIT
1	t ₁	Delay time, ENx high to OUTx high, INx = 1	130	330	ns
2	t ₂	Delay time, ENx low to OUTx low, INx = 1	275	475	ns
3	t ₃	Delay time, ENx high to OUTx low, INx = 0	100	300	ns
4	t ₄	Delay time, ENx low to OUTx high, INx = 0	200	400	ns
5	t ₅	Delay time, INx high to OUTx high	300	500	ns
6	t ₆	Delay time, INx low to OUTx low	275	475	ns
7	t _r	Output rise time, resistive load to GND	30	150	ns
8	t _f	Output fall time, resistive load to GND	30	150	ns

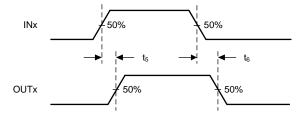
(1) Not production tested



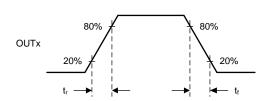
INx = 1, Resistive Load to GND



INx = 0, Resistive Load to VM



ENx = 1, Resistive Load to GND



T0543-01

Figure 1. DRV8313 Switching Characteristics

Submit Documentation Feedback



FUNCTIONAL DESCRIPTION

Output Stage

The DRV8313 contains three half-H-bridge drivers. The source terminals of the low-side FETs of all three half-H-bridges terminate at separate pins (GND1, GND2, and GND3) to allow the use of a low-side current-sense resistor on each output, if desired. The user may also connect all three together to a single low-side sense resistor, or may connect them directly to ground if there is no need for current sensing.

If using a low-side sense resistor, take care to ensure that the voltage on the GND1, GND2, or GND3 pin does not exceed ±500 mV.

Note that there are multiple VM motor power-supply pins. Connect all VM pins together to the motor-supply voltage.

Bridge Control

The INx input pins directly control the state (high or low) of the OUTx outputs; the ENx input pins enable or disable the OUTx driver. The following table shows the logic:

INx	ENx	OUTx
Х	0	Z
0	1	L
1	1	Н

Charge Pump

Because the output stages use N-channel FETs, the device requires a gate-drive voltage higher than the VM power supply to enhance the high-side FETs fully. The DRV8313 integrates a charge-pump circuit that generates a voltage above the VM supply for this purpose.

The charge pump requires two external capacitors for operation. See the block diagram and pin descriptions for details on these capacitors (value, connection, and so forth).

The charge pump shuts down when nSLEEP is active-low.

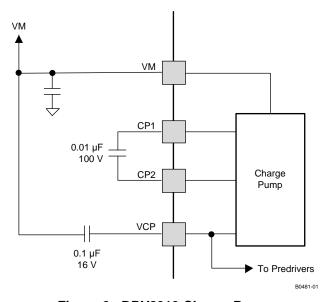


Figure 2. DRV8313 Charge Pump



Comparator

The DRV8313 includes an uncommitted comparator, which can find use as a current-limit comparator or for other purposes.

The following diagram shows connections to use the comparator to sense current for implementing a current limit. Current from all three low-side FETs is sensed using a single low-side sense resistor. The voltage across the sense resistor is compared with a reference, and when the sensed voltage exceeds the reference, a current-limit condition is signaled to the controller. The V3P3OUT internal voltage regulator can be used to set the reference voltage of the comparator.

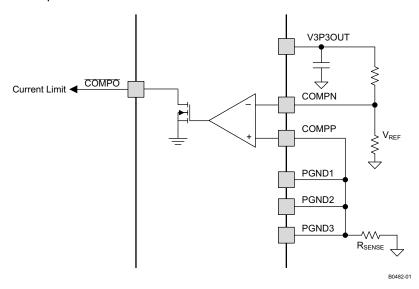


Figure 3. DRV8313 Comparator

nRESET and nSLEEP Operation

The nRESET pin, when driven active-low, resets any faults. It also disables the output drivers while it is active. The device ignores all inputs while nRESET is active. Note that there is an internal power-up-reset circuit, so that driving nRESET at power up is not required.

Driving nSLEEP low puts the device into a low-power sleep state. Entering this state disables the output drivers, stops the gate-drive charge pump, resets all internal logic (including faults), and stops all internal clocks. In this state, the device ignores all inputs until nSLEEP returns inactive-high. When returning from sleep mode, some time (approximately 1 ms) must pass before the motor driver becomes fully operational. Note that the V3P3 regulator remains operational in sleep mode.

Protection Circuits

The DRV8313 has full protection against undervoltage, overcurrent, and overtemperature events.

OVERCURRENT PROTECTION (OCP)

An analog current-limit circuit on each FET limits the current through the FET by removing the gate drive. If this analog current limit persists for longer than the OCP deglitch time, the device disables the channel experiencing the overcurrent and drives the nFAULT pin low. The driver remains off until either assertion of nRESET or the cycling of VM power.

Overcurrent conditions on both high- and low-side devices, that is, a short to ground, supply, or across the motor winding, all result in an overcurrent shutdown.

THERMAL SHUTDOWN (TSD)

If the die temperature exceeds safe limits, the device disables all outputs and drives the nFAULT pin low. Once the die temperature has fallen to a safe level, operation automatically resumes.



UNDERVOLTAGE LOCKOUT (UVLO)

If at any time the voltage on the VM pins falls below the undervoltage-lockout threshold voltage, the device disables all outputs, resets internal logic, and drives the nFAULT pin low. Operation resumes when VM rises above the UVLO threshold.

THERMAL INFORMATION

Thermal Protection

The DRV8313 has thermal shutdown (TSD) as previously described. A die temperature in excess of approximately 150°C disables the device until the temperature drops to a safe level.

Any tendency of the device to enter thermal shutdown is an indication of excessive power dissipation, insufficient heatsinking, or too high an ambient temperature.

Power Dissipation

The power dissipated in the output FET resistance, or $r_{DS(on)}$ dominates power dissipation in the DRV8313. A rough estimate of average power dissipation of each half-H-bridge when running a static load is:

$$P = r_{DS(on)} \times (I_{OUT})^2$$
(1)

where P is the power dissipation of one H-bridge, $r_{DS(on)}$ is the resistance of each FET, and I_{OUT} is equal to the average current drawn by the load. Note that at start-up and fault conditions, this current is much higher than normal running current; remember to take these peak currents and their duration into consideration.

The total device dissipation is the power dissipated in each of the three half-H-bridges added together.

The maximum amount of power that the device can dissipate depends on ambient temperature and heatsinking.

Note that $r_{DS(on)}$ increases with temperature, so as the device heats, the power dissipation increases. Take this into consideration when sizing the heatsink.

Heatsinking

The PowerPAD package uses an exposed pad to remove heat from the device. For proper operation, this pad must be thermally connected to copper on the PCB to dissipate heat. On a multi-layer PCB with a ground plane, add a number of vias to connect the thermal pad to the ground plane to accomplish this. On PCBs without internal planes, add copper area on either side of the PCB to dissipate heat. If the copper area is on the opposite side of the PCB from the device, use thermal vias to transfer the heat between the top and bottom layers.

For details about how to design the PCB, see TI Application Report SLMA002, *PowerPAD Thermally Enhanced Package* and TI Application Brief SLMA004, *PowerPAD Made Easy*, available at www.ti.com.

In general, providing more copper area allows the dissipation of more power.



APPLICATION INFORMATION

Output Configurations and Connections

The typical application for the DRV8313 is to drive a 3-phase brushless motor. In this application, the three outputs connect to the three motor leads, as shown in Figure 4.

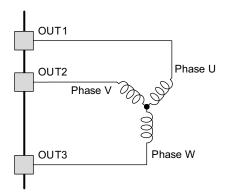


Figure 4. Three-Phase Motor Connection

The device achieves standard 120° (also called trapezoidal or block) commutation, using synchronous rectification, by following the states shown in Table 1

Table 1. Three-Phase Motor Signals

State	0	UT1 (Phase	U)	c	OUT2 (Phase '	V)	OUT3 (Phase W)			
	IN1	EN1	OUT1	IN2	EN2	OUT2	IN3	EN3	OUT3	
1	Х	0	Z	1 / PWM	1	H / PWM	0	1	L	
2	1 / PWM	1	H / PWM	Х	0	Z	0	1	L	
3	1 / PWM	1	H / PWM	0	1	L	Х	0	Z	
4	Х	0	Z	0	1	L	1 / PWM	1	H / PWM	
5	0	1	L	Х	0	Z	1 / PWM	1	H / PWM	
6	0	1	L	1 / PWM	1	H / PWM	Х	0	Z	

On can implement asynchronous rectification by also applying the PWM signal to the enable inputs.

The DRV8313 can drive other loads, including dc brush motors and solenoids. For example, one could drive a dc brush motor in both directions, plus a single solenoid or unidirectional dc brush motor:

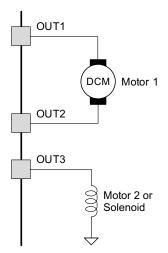


Figure 5. Bidirectional Motor Plus Motor or Solenoid Connection



The functions would be as shown in Table 2.

Table 2. Bidirectional Motor Plus Motor or Solenoid Signals

			Motor 2 or Solenoid							
Function	IN1	EN1	OUT1	IN2	EN2	OUT2	Function	IN3	EN3	OUT3
Off or coast	Х	0	Z	Х	Х	Х	On	1 / PWM	1	1
Off or coast	Х	Х	Х	Х	0	Х	Off or slow decay	0	1	0
Forward	1 / PWM	1	1	0	1	0	Off or coast	Х	0	Х
Reverse	0	1	0	1 / PWM	1	1				
Brake or slow decay	0	1	0	0	1	0				
Brake or slow decay	1	1	1	1	1	1				

Applying a PWM signal to the appropriate INx pin(s) as shown in Table 2 could implement PWM speed control.

Another possibility is controlling three different loads. Note that it is possible to return one side of the load either to the power supply (VM) or to ground.

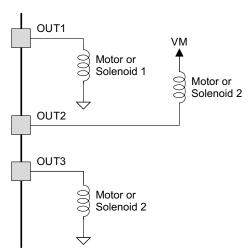


Figure 6. Three Independent Load Connections

Table 3. Three Independent Load Signals

Motor or Solenoid 1				Motor or Solenoid 2				Motor or Solenoid 3			
Function	Function IN1 EN1 OUT1				IN2	EN2	OUT2	Function	IN3	EN3	OUT3
On	1 / PWM	1	1	On	1 / PWM	1	1	On	1 / PWM	1	1
Off or slow decay	0	1	0	Off or slow decay	0	1	0	Off or slow decay	0	1	0
Off or coast	Х	0	Х	Off or coast	Х	0	Х	Off or coast	Х	0	Х



PACKAGE OPTION ADDENDUM

11-Apr-2013

PACKAGING INFORMATION

Orderable Device		Package Type	Package Drawing	Pins	Package Qty	Eco Plan	Lead/Ball Finish	MSL Peak Temp	Op Temp (°C)	Top-Side Markings	Samples
	(1)		Drawing		Qty	(2)		(3)		(4)	
DRV8313PWP	ACTIVE	HTSSOP	PWP	28	50	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	DRV8313	Samples
DRV8313PWPR	ACTIVE	HTSSOP	PWP	28	2000	Green (RoHS & no Sb/Br)	CU NIPDAU	Level-3-260C-168 HR	-40 to 85	DRV8313	Samples

(1) The marketing status values are defined as follows:

ACTIVE: Product device recommended for new designs.

LIFEBUY: TI has announced that the device will be discontinued, and a lifetime-buy period is in effect.

NRND: Not recommended for new designs. Device is in production to support existing customers, but TI does not recommend using this part in a new design.

PREVIEW: Device has been announced but is not in production. Samples may or may not be available.

OBSOLETE: TI has discontinued the production of the device.

(2) Eco Plan - The planned eco-friendly classification: Pb-Free (RoHS), Pb-Free (RoHS Exempt), or Green (RoHS & no Sb/Br) - please check http://www.ti.com/productcontent for the latest availability information and additional product content details.

TBD: The Pb-Free/Green conversion plan has not been defined.

Pb-Free (RoHS): TI's terms "Lead-Free" or "Pb-Free" mean semiconductor products that are compatible with the current RoHS requirements for all 6 substances, including the requirement that lead not exceed 0.1% by weight in homogeneous materials. Where designed to be soldered at high temperatures, TI Pb-Free products are suitable for use in specified lead-free processes.

Pb-Free (RoHS Exempt): This component has a RoHS exemption for either 1) lead-based flip-chip solder bumps used between the die and package, or 2) lead-based die adhesive used between the die and leadframe. The component is otherwise considered Pb-Free (RoHS compatible) as defined above.

Green (RoHS & no Sb/Br): TI defines "Green" to mean Pb-Free (RoHS compatible), and free of Bromine (Br) and Antimony (Sb) based flame retardants (Br or Sb do not exceed 0.1% by weight in homogeneous material)

(3) MSL, Peak Temp. -- The Moisture Sensitivity Level rating according to the JEDEC industry standard classifications, and peak solder temperature.

(4) Multiple Top-Side Markings will be inside parentheses. Only one Top-Side Marking contained in parentheses and separated by a "~" will appear on a device. If a line is indented then it is a continuation of the previous line and the two combined represent the entire Top-Side Marking for that device.

Important Information and Disclaimer: The information provided on this page represents TI's knowledge and belief as of the date that it is provided. TI bases its knowledge and belief on information provided by third parties, and makes no representation or warranty as to the accuracy of such information. Efforts are underway to better integrate information from third parties. TI has taken and continues to take reasonable steps to provide representative and accurate information but may not have conducted destructive testing or chemical analysis on incoming materials and chemicals. TI and TI suppliers consider certain information to be proprietary, and thus CAS numbers and other limited information may not be available for release.

In no event shall TI's liability arising out of such information exceed the total purchase price of the TI part(s) at issue in this document sold by TI to Customer on an annual basis.

PACKAGE MATERIALS INFORMATION

www.ti.com 26-Jan-2013

TAPE AND REEL INFORMATION





	Dimension designed to accommodate the component width
	Dimension designed to accommodate the component length
K0	Dimension designed to accommodate the component thickness
W	Overall width of the carrier tape
P1	Pitch between successive cavity centers

QUADRANT ASSIGNMENTS FOR PIN 1 ORIENTATION IN TAPE



*All dimensions are nominal

Device	Package Type	Package Drawing			Reel Diameter (mm)	Reel Width W1 (mm)	A0 (mm)	B0 (mm)	K0 (mm)	P1 (mm)	W (mm)	Pin1 Quadrant
DRV8313PWPR	HTSSOP	PWP	28	2000	330.0	16.4	6.9	10.2	1.8	12.0	16.0	Q1

www.ti.com 26-Jan-2013



*All dimensions are nominal

Device Package Type		Package Drawing	Pins	SPQ	Length (mm)	Width (mm)	Height (mm)	
DRV8313PWPR	HTSSOP	PWP	28	2000	367.0	367.0	38.0	

PWP (R-PDSO-G28)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- All linear dimensions are in millimeters.
- This drawing is subject to change without notice.
- Body dimensions do not include mold flash or protrusions. Mold flash and protrusion shall not exceed 0.15 per side.
- This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 for information regarding recommended board layout. This document is available at www.ti.com www.ti.com.

 E. See the additional figure in the Product Data Sheet for details regarding the exposed thermal pad features and dimensions.
- E. Falls within JEDEC MO-153

PowerPAD is a trademark of Texas Instruments.



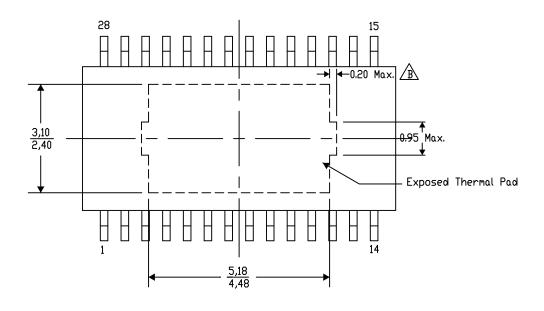
PWP (R-PDSO-G28) PowerPAD™ SMALL PLASTIC OUTLINE

THERMAL INFORMATION

This PowerPAD[™] package incorporates an exposed thermal pad that is designed to be attached to a printed circuit board (PCB). The thermal pad must be soldered directly to the PCB. After soldering, the PCB can be used as a heatsink. In addition, through the use of thermal vias, the thermal pad can be attached directly to the appropriate copper plane shown in the electrical schematic for the device, or alternatively, can be attached to a special heatsink structure designed into the PCB. This design optimizes the heat transfer from the integrated circuit (IC).

For additional information on the PowerPAD package and how to take advantage of its heat dissipating abilities, refer to Technical Brief, PowerPAD Thermally Enhanced Package, Texas Instruments Literature No. SLMA002 and Application Brief, PowerPAD Made Easy, Texas Instruments Literature No. SLMA004. Both documents are available at www.ti.com.

The exposed thermal pad dimensions for this package are shown in the following illustration.



Top View

Exposed Thermal Pad Dimensions

4206332-38/AD 01/13

NOTE: A. All linear dimensions are in millimeters

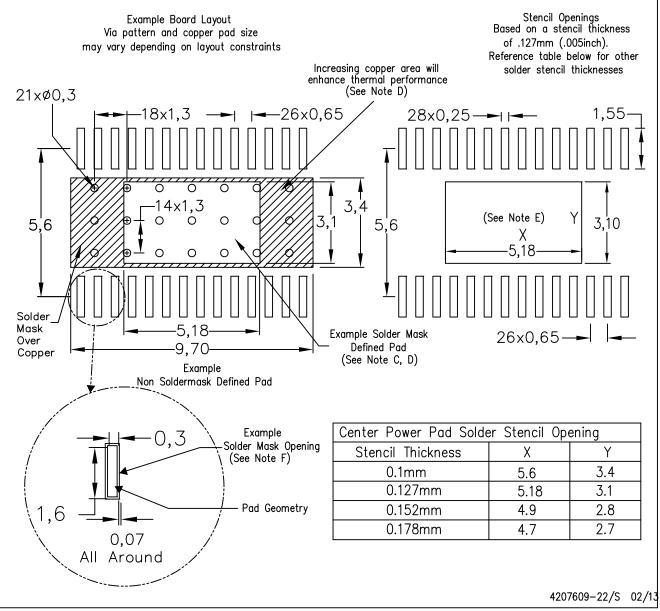
A Exposed tie strap features may not be present.

PowerPAD is a trademark of Texas Instruments



PWP (R-PDSO-G28)

PowerPAD™ PLASTIC SMALL OUTLINE



NOTES:

- A. All linear dimensions are in millimeters.
- B. This drawing is subject to change without notice.
- C. Customers should place a note on the circuit board fabrication drawing not to alter the center solder mask defined pad.
- D. This package is designed to be soldered to a thermal pad on the board. Refer to Technical Brief, PowerPad Thermally Enhanced Package, Texas Instruments Literature No. SLMA002, SLMA004, and also the Product Data Sheets.
- E. For specific thermal information, via requirements, and recommended board layout. These documents are available at www.ti.com www.ti.com. Publication IPC-7351 is recommended for alternate designs. Laser cutting apertures with trapezoidal walls and also rounding corners will offer better paste release. Customers should contact their board assembly site for stencil design recommendations. Example stencil design based on a 50% volumetric metal load solder paste. Refer to IPC-7525 for other stencil
- F. Customers should contact their board fabrication site for solder mask tolerances between and around signal pads.



IMPORTANT NOTICE

Texas Instruments Incorporated and its subsidiaries (TI) reserve the right to make corrections, enhancements, improvements and other changes to its semiconductor products and services per JESD46, latest issue, and to discontinue any product or service per JESD48, latest issue. Buyers should obtain the latest relevant information before placing orders and should verify that such information is current and complete. All semiconductor products (also referred to herein as "components") are sold subject to TI's terms and conditions of sale supplied at the time of order acknowledgment.

TI warrants performance of its components to the specifications applicable at the time of sale, in accordance with the warranty in TI's terms and conditions of sale of semiconductor products. Testing and other quality control techniques are used to the extent TI deems necessary to support this warranty. Except where mandated by applicable law, testing of all parameters of each component is not necessarily performed.

TI assumes no liability for applications assistance or the design of Buyers' products. Buyers are responsible for their products and applications using TI components. To minimize the risks associated with Buyers' products and applications, Buyers should provide adequate design and operating safeguards.

TI does not warrant or represent that any license, either express or implied, is granted under any patent right, copyright, mask work right, or other intellectual property right relating to any combination, machine, or process in which TI components or services are used. Information published by TI regarding third-party products or services does not constitute a license to use such products or services or a warranty or endorsement thereof. Use of such information may require a license from a third party under the patents or other intellectual property of the third party, or a license from TI under the patents or other intellectual property of TI.

Reproduction of significant portions of TI information in TI data books or data sheets is permissible only if reproduction is without alteration and is accompanied by all associated warranties, conditions, limitations, and notices. TI is not responsible or liable for such altered documentation. Information of third parties may be subject to additional restrictions.

Resale of TI components or services with statements different from or beyond the parameters stated by TI for that component or service voids all express and any implied warranties for the associated TI component or service and is an unfair and deceptive business practice. TI is not responsible or liable for any such statements.

Buyer acknowledges and agrees that it is solely responsible for compliance with all legal, regulatory and safety-related requirements concerning its products, and any use of TI components in its applications, notwithstanding any applications-related information or support that may be provided by TI. Buyer represents and agrees that it has all the necessary expertise to create and implement safeguards which anticipate dangerous consequences of failures, monitor failures and their consequences, lessen the likelihood of failures that might cause harm and take appropriate remedial actions. Buyer will fully indemnify TI and its representatives against any damages arising out of the use of any TI components in safety-critical applications.

In some cases, TI components may be promoted specifically to facilitate safety-related applications. With such components, TI's goal is to help enable customers to design and create their own end-product solutions that meet applicable functional safety standards and requirements. Nonetheless, such components are subject to these terms.

No TI components are authorized for use in FDA Class III (or similar life-critical medical equipment) unless authorized officers of the parties have executed a special agreement specifically governing such use.

Only those TI components which TI has specifically designated as military grade or "enhanced plastic" are designed and intended for use in military/aerospace applications or environments. Buyer acknowledges and agrees that any military or aerospace use of TI components which have *not* been so designated is solely at the Buyer's risk, and that Buyer is solely responsible for compliance with all legal and regulatory requirements in connection with such use.

TI has specifically designated certain components as meeting ISO/TS16949 requirements, mainly for automotive use. In any case of use of non-designated products, TI will not be responsible for any failure to meet ISO/TS16949.

Products Applications

Audio www.ti.com/audio Automotive and Transportation www.ti.com/automotive Communications and Telecom **Amplifiers** amplifier.ti.com www.ti.com/communications **Data Converters** dataconverter.ti.com Computers and Peripherals www.ti.com/computers **DLP® Products** www.dlp.com Consumer Electronics www.ti.com/consumer-apps

DSP **Energy and Lighting** dsp.ti.com www.ti.com/energy Clocks and Timers www.ti.com/clocks Industrial www.ti.com/industrial Interface interface.ti.com Medical www.ti.com/medical logic.ti.com Logic Security www.ti.com/security

Power Mgmt power.ti.com Space, Avionics and Defense www.ti.com/space-avionics-defense

Microcontrollers microcontroller.ti.com Video and Imaging www.ti.com/video

RFID www.ti-rfid.com

OMAP Applications Processors <u>www.ti.com/omap</u> TI E2E Community <u>e2e.ti.com</u>

Wireless Connectivity <u>www.ti.com/wirelessconnectivity</u>

Mouser Electronics

Authorized Distributor

Click to View Pricing, Inventory, Delivery & Lifecycle Information:

Texas Instruments:

DRV8313PWPR DRV8313PWP